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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/721,524	11/25/2003	Richard A. Blanchard	03-C-040 (850063.602)	5333
30423 7590 12/14/2007 STMICROELECTRONICS, INC. MAIL STATION 2346 1310 ELECTRONICS DRIVE CARROLLTON, TX 75006			EXAMINER DICKEY, THOMAS L	
			ART UNIT 2826	PAPER NUMBER
			MAIL DATE 12/14/2007	DELIVERY MODE PAPER

**Please find below and/or attached an Office communication concerning this application or proceeding.**

The time period for reply, if any, is set in the attached communication.

# Office Action Summary

Application No.

10/721,524

Applicant(s)

BLANCHARD ET AL.

Examiner

Thomas L. Dickey

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-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

## Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

## Status

- 1) ☒ Responsive to communication(s) filed on 30 November 2007.
- 2a) ☒ This action is **FINAL**. 2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

## Disposition of Claims

- 4) ☐ Claim(s) 13-27, 34-47 and 50-52 is/are pending in the application.
- 4a) Of the above claim(s) \_\_\_\_\_ is/are withdrawn from consideration.
- 5) ☒ Claim(s) 13-27 and 34-46 is/are allowed.
- 6) ☒ Claim(s) 47 and 50-52 is/are rejected.
- 7) ☐ Claim(s) \_\_\_\_\_ is/are objected to.
- 8) ☐ Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

## Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 25 November 2003 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.  
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

## Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some \* c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- \* See the attached detailed Office action for a list of the certified copies not received.

## Attachment(s)

- 1) ☐ Notice of References Cited (PTO-892)
- 2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
- 3) ☐ Information Disclosure Statement(s) (PTO/SB/08)  
Paper No(s)/Mail Date \_\_\_\_\_.
- 4) ☐ Interview Summary (PTO-413)  
Paper No(s)/Mail Date \_\_\_\_\_.
- 5) ☐ Notice of Informal Patent Application
- 6) ☐ Other: \_\_\_\_\_.

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## DETAILED ACTION

1. The amendment filed on 11/30/2007 has been entered.

### ***Claim Rejections - 35 USC § 103***

2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

Claims 47 and 50-52 stand rejected under 35 U.S.C. 103(a) as being unpatentable over CHAN ET AL. (5,917,226) in view of Shaw et al. (5,847,454).

With regard to claim 47 Chan et al. discloses a beam structure comprising a semiconductor substrate 21'; a first conducting layer 23', a beam 20 positioned relative to the substrate 21', the beam 20 being connected at a first portion 24' thereof to the substrate 21'; the beam 20 being movable at a second portion 26'; a remaining sacrificial layer 25' (the right of the two layers marked 25') between the first portion 24' of the beam 20 and the substrate 21'; and a circuit 12 configured to detect electrical contact between the second portion 26' of the beam 20 and the first conducting layer.

Note figures 1,3,5, and column 6 lines 14-67 of Chan et al. Chan et al. does not disclose

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that positioning beam 20 within a trench having walls extending into the semiconductor substrate 21', positioning first conducting layer 23' over the walls of the trench at selected locations and spacing second portion 26' from the walls of the trench by a selected distance.

However, Shaw et al. discloses a method of forming a beam structure comprising positioning beam 52 within a trench 54 having walls 78 extending into semiconductor substrate 50, positioning a first conducting layer 78 (same # but different part from the walls) over the walls 78 of trench 54 at selected locations and spacing a second portion 74 from the walls of the trench 54 by a selected distance. Note figures 1A-1J, 3, column 13 lines 36-48, and column 14 lines 1-41 of Shaw et al. It would have been obvious to a person having skill in the art to modify Chan et al.'s beam structure by using the trenching method taught by Shaw et al. to position Chan et al.'s beam 20 within a trench having walls extending into semiconductor substrate 21', positioning first conducting layer 23' over the walls of the trench at selected locations and spacing a second portion 26' from the walls of the trench by a selected distance, thus achieving the claimed invention. It is noted that Shaw et al. teaches, "The process of the present invention permits fabrication of integrated structures, wherein released beams and other microelectromechanical structures may be interconnected with an on-chip integrated circuit (IC). In accordance with this modification of the process, which is illustrated in

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FIGS. 5A-5I, an integrated circuit 12 wafer can be batch fabricated using standard integrated circuit technologies to produce desired circuits and circuit components on the wafer, and thereafter a microelectromechanical device can be fabricated on the wafer utilizing the process of the present invention without varying the standard IC technology" (column 14 lines 46-54); and that "Any kind of integrated circuit can be on the wafer for connection to the released structure" (column 15 lines 31-34). From these statements it is possible to infer that application of Shaw et al.'s trenching technique can be applied to modify Chan et al.'s combination of beam 20 and circuit 12 with a reasonable expectation of successfully producing the claimed device. The Examiner explicitly states that the reason (See *KSR International Co. v. Teleflex Inc.*, 550 U. S. \_\_\_ (2007), slip op. at 14) the combination would have been obvious is that the claimed combination is nothing more than the application of a known technique (the trenching method of Shaw et al.) to a piece of prior art (Chan et al.'s) ready for improvement, with a reasonable expectation of success.

In a case such as this one, "where an improvement is no more than '... the mere application of a known technique to a piece of prior art ready for improvement,' *KSR Int'l Co. v. Teleflex Inc.*, [127 S.Ct. 1727, 1740, 82 USPQ2d 1385, 1396 (2007)], no further analysis is required of the Examiner." *Ex parte Smith*, 83 USPQ2d 1509, 1518 (Bd. Pat.

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App. & Int. 2007) (Or see Slip Op., available at <http://www.uspto.gov/web/offices/dcom/bpai/prec/fd071925.pdf>, at 21).

With regard to claims 50-52 Chan et al. discloses a beam structure comprising a semiconductor substrate 21'; a beam 20 positioned relative to the substrate 21', coupled to the substrate 21' at a first portion 24' and a third portion 25' (on the left, opposite part 24') thereof and movable with respect to the substrate 21' at a second portion 26' thereof located between the first 24' and third 25' portions; and means comprising an electrical circuit 12 having a first input coupled to the beam 20 and a second input coupled to the substrate 21', the electrical circuit 12 configured to detect electrical continuity between the first and second inputs, for detecting contact between the second portion 26' of the beam 20 and the substrate 21'. Note figures 1,3,5, and column 6 lines 14-67 of Chan et al. Chan et al. does not disclose positioning beam 20 within a trench extending in semiconductor substrate 21', or making the contact between the second portion 26' of the beam 20 and the substrate 21' at a wall of the trench.

However, Shaw et al. discloses a method of forming a beam structure comprising positioning beam 52 within a trench 54 extending in semiconductor substrate 50, and making contact between a second portion 26' of the beam 52 and the substrate 50 at a wall 78 of the trench 54. Note figures 1A-1J, 3, column 13 lines 36-48, and column 14 lines 1-41 of Shaw et al. It would have been obvious to a person having skill in the art to

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modify Chan et al.'s beam structure by using the trenching method taught by Shaw et al. to position beam 20 within a trench extending in semiconductor substrate 21', and making contact between second portion 26' of beam 20 and the substrate 50 at a wall of the trench, thus achieving the claimed invention. It is noted that Shaw et al. teaches, "The process of the present invention permits fabrication of integrated structures, wherein released beams and other microelectromechanical structures may be interconnected with an on-chip integrated circuit 12 (IC). In accordance with this modification of the process, which is illustrated in FIGS. 5A-5I, an integrated circuit wafer can be batch fabricated using standard integrated circuit technologies to produce desired circuits and circuit components on the wafer, and thereafter a microelectromechanical device can be fabricated on the wafer utilizing the process of the present invention without varying the standard IC technology" (column 14 lines 46-54); and that "Any kind of integrated circuit can be on the wafer for connection to the released structure" (column 15 lines 31-34). From these statements it is possible to infer that application of Shaw et al.'s trenching technique can be applied to modify Chan et al.'s combination of beam 20 and circuit 12 with a reasonable expectation of successfully producing the claimed device. The Examiner explicitly states that the reason (See *KSR International Co. v. Teleflex Inc.*, 550 U. S. \_\_\_ (2007), slip op. at 14) the combination would have been obvious is that the claimed combination is nothing

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more than the application of a known technique (the trenching method of Shaw et al.) to a piece of prior art (Chan et al.'s) ready for improvement, with a reasonable expectation of success.

In a case such as this one, "where an improvement is no more than '... the mere application of a known technique to a piece of prior art ready for improvement,' *KSR Int'l Co. v. Teleflex Inc.*, [127 S.Ct. 1727, 1740, 82 USPQ2d 1385, 1396 (2007)], no further analysis is required of the Examiner." *Ex parte Smith*, 83 USPQ2d 1509, 1518 (Bd. Pat. App. & Int. 2007) (Or see Slip Op., available at <http://www.uspto.gov/web/offices/dcom/bpai/prec/fd071925.pdf>, at 21).

### ***Allowable Subject Matter***

3. Claim 13-27 and 34-46 are allowed over the references of record for the reasons recited in the action mailed 11/17/2006.

### ***Response to Arguments***

4. Applicant's arguments filed 11/30/2007 have been fully considered but they are not persuasive.

It is argued, at page 2 of the remarks, that "First, each reference teaches away from such a combination. Shaw's device [is an analog device, whereas] Chan is a purely



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binary, i.e., digital device." These statements are completely irrelevant to the reasoning employed in the rejection actually made. The Examiner previously stated (and continues to state, see section II, above): "the claimed combination is nothing more than the application of a known technique (the trenching method of Shaw et al.) to a piece of prior art (Chan et al.'s) ready for improvement, with a reasonable expectation of success." The Examiner has quoted the relied-upon sections of Shaw et al. twice, so far, and does so again, for the record, now, with emphasis added at the points Applicant simply ignores in his argument: Shaw et al. teaches, "The process of the present [i.e. Shaw et al.'s] invention permits fabrication of integrated structures, wherein released beams and other microelectromechanical structures may be interconnected with an on-chip integrated circuit (IC). In accordance with this modification of the process, which is illustrated in FIGS. 5A-5I, an integrated circuit wafer can be batch fabricated using standard integrated circuit technologies to produce desired circuits and circuit components on the wafer, and thereafter a microelectromechanical device can be fabricated on the wafer utilizing the process of the present invention without varying the standard IC technology" (column 14 lines 46-54). Applicant will please note that the type of device Shaw et al. apply their technique to is totally irrelevant, so long as there is evidence the technique would have been applicable to Chan et al.'s device with "a

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reasonable expectation of success.” (note that this is the standard set in KSR for the application of a known technique to a known device ready for improvement.)

Note further that Shaw et al. explicitly states, “Any kind of integrated circuit can be on the wafer for connection to the released structure” (column 15 lines 31-34). How can Applicant reasonably argue that Shaw et al.’s trenching technique cannot be successfully applied to Chan et al.’s device because “Chan is a purely binary, i.e., digital device?” Shaw et al. explicitly states that the technique may be applied to “any kind of integrated circuit.” What part of Shaw et al.’s phrase “Any kind of integrated circuit” persuaded Applicant that “binary, i.e., digital devices” were excluded?

It is argued, at page 3 of the remarks, that “Second, a combination of Shaw and Chan would render one or the other unsuitable for its intended purpose (see MPEP § 2143.01, subsection V ([i]f [a] proposed modification would render the prior art invention being modified unsatisfactory for its intended purpose, then there is no suggestion or motivation to make the proposed modification)). Shaw’s device is intended primarily to operate as an accelerometer or actuator (see Shaw, 3:42-47) that operates across a ‘wide range of motion or sensitivity.’ Id., 5:40, 41. Chan’s device is intended to operate as a thermal sensor.”

The Examiner explicitly states (as he has done twice already) that the reason (see *KSR International Co. v. Teleflex Inc.*, 550 U. S. \_\_\_\_ (2007), slip op. at 14) the

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combination would have been obvious is that the claimed combination is nothing more than the application of a known technique (the trenching method of Shaw et al.) to a piece of prior art (Chan et al.'s) ready for improvement, with a reasonable expectation of success.

The Examiner has written these words before (twice). Applicant has ignored these words (twice). Will a third attempt succeed in communicating to Applicant that the rejection is grounded in applying Shaw's technique to Chan et al.'s device? The rejection in no way attempts to combine Shaw's accelerometer with Chan et al.'s thermal sensor, nor is it in any way necessary to combine these devices to reach the claimed invention.

It is argued, at page 4 of the remarks, that "KSR teaches that 'a court [or Examiner] must ask whether the improvement is more than the predictable use of prior art elements *according to their established functions*. KSR, 127 S.Ct., at 1740 (emphasis added)." However, also on page 1740, KSR holds, "**[I]f a technique has been used to improve one device, and a person of ordinary skill in the art would recognize that it would improve similar devices in the same way, using the technique is obvious unless its actual application is beyond his or her skill.**" KSR, 127 S.Ct., also at 1740 (emphasis also added). Is it

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ethical, in the strictest sense, to cite a portion of a particular page of a case against a rejection without also citing the portion of the exact same page of that case that supports the rejection?

It is argued, at page 6 of the remarks, that "Even if, as the Examiner notes, Shaw teaches that its devices can be integrated with a wide range of other micromechanical structures and circuits on a common substrate (Office Action, page 4), integration of Chan's device on a common substrate with Shaw's would merely result in two separate and independent devices, side-by-side, and would not produce a device as claimed in the present application, under any reasonable circumstances." In so arguing, Applicant displays a degree of ignorance that seems to have been acquired almost willfully.

Nowhere does the Examiner suggest "integration of Chan's device on a common substrate with Shaw's." Rather, the Examiner has shown that the Shaw et al. reference demonstrates that at the time of the invention persons of ordinary skill in the art had at their disposal a particular technique that would have been recognized to be capable of improving Chan et al.'s device in the same way it improved Shaw et al.'s, and that the evidence shows that the Shaw et al. reference teaches all that is needed to place actual application of this technique within the skill of persons of ordinary skill in the art. In a case such as this one, "where an improvement is no more than '... the mere application of a known technique to a piece of prior art ready for improvement,' *KSR Int'l Co. v.*

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*Teleflex Inc.*, [127 S.Ct. 1727, 1740, 82 USPQ2d 1385, 1396 (2007)], no further analysis is required of the Examiner." *Ex parte Smith*, 83 USPQ2d 1509, 1518 (Bd. Pat. App. & Int. 2007).

### ***Conclusion***

**5. THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

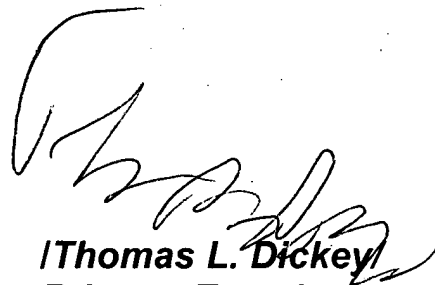
A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thomas L. Dickey whose telephone number is 571-272-1913. The examiner can normally be reached on Monday-Thursday 8-6.

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If attempts to reach the examiner by telephone are unsuccessful, please contact the examiner's supervisor, Sue A. Purvis, at 571-272-1236. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).



**/Thomas L. Dickey**  
**Primary Examiner**  
**Art Unit 2826**